

Description

The AU0521P0 is a bi-directional TVS diode, utilizing leading monolithic silicon technology to provide fast response time and low ESD clamping voltage, making this device an ideal solution for protecting voltage sensitive data and power line. The AU0521P0 complies with the IEC 61000-4-2 (ESD) with ±30kV air and ±30kV contact discharge. It is assembled into an ultra-small 0.6x0.3x0.3mm lead-free DFN package. The ultra small size and high ESD surge protection make AU0521P0 an ideal choice to replace 0201 size multilayer varistors (MLVs) and protect cell phone, digital cameras, audio players and many other portable applications.

Features

Ultra small package: 0.6x0.3x0.3mm

Very low capacitance

Protects one data or power line

Ultra low leakage: nA level

Operating voltage: 5V

Low clamping voltage

2-pin leadless package

Complies with following standards:

IEC 61000-4-2 (ESD) immunity test
Air discharge: ±30kV
Contact discharge: ±30kV

– IEC61000-4-5 (Lightning) 8A (8/20μs)

RoHS Compliant

Mechanical Characteristics

Package: DFN0603-2 (0.6×0.3×0.3mm)

• Case Material: "Green" Molding Compound.

Terminal Connections: See Diagram Below

· Marking Information: See Below

Applications

- Cellular Handsets and Accessories
- Personal Digital Assistants
- Notebooks and Handhelds
- Portable Instrumentation
- Digital Cameras
- Peripherals
- Audio Players

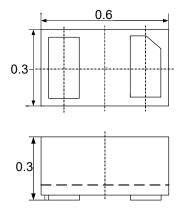
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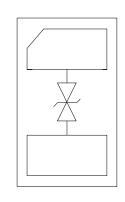
Marking Information

5A

5A = Device Marking Code

Dimensions and Pin Configuration





Package Dimensions

Circuit and Pin Schematic

Ordering Information

Part Number	Packaging	Reel Size
AU0521P0	10000/Tape & Reel	7 inch



Absolute Maximum Ratings (T_A=25°C unless otherwise specified)

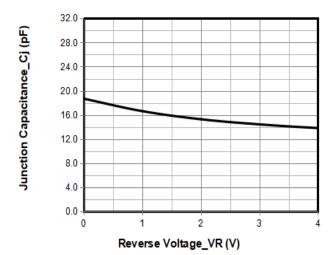
Parameter	Symbol	Value	Unit
Peak Pulse Power (8/20µs)	Ppk	100	W
Peak Pulse Current (8/20µs)	Ipp	8	Α
ESD per IEC 61000-4-2 (Air)	VESD	±30	kV
ESD per IEC 61000-4-2 (Contact)	VESD	±30	N.V
Operating Temperature Range	TJ	−55 to +125	°C
Storage Temperature Range	Tstg	-55 to +150	°C

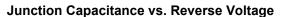
Electrical Characteristics (T_A=25°C unless otherwise specified)

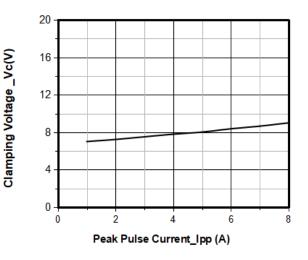
Parameter	Symbol	Min	Тур	Max	Unit	Test Condition
Reverse Working Voltage	VRWM			5	V	
Breakdown Voltage	VBR	6		8	V	IT = 1mA
Reverse Leakage Current	I _R			0.1	μA	VRWM = 5V
Clamping Voltage	Vc			8.5	V	IPP = 1A (8 x 20μs pulse)
Clamping Voltage	Vc			12.5	V	IPP = 8A (8 x 20µs pulse)
Junction Capacitance	Cl			20	pF	VR = 0V, f = 1MHz



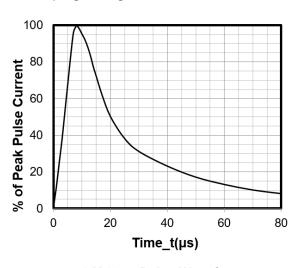
Typical Performance Characteristics (TA=25°C unless otherwise Specified)



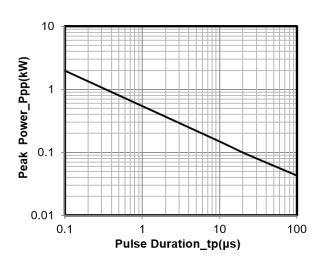




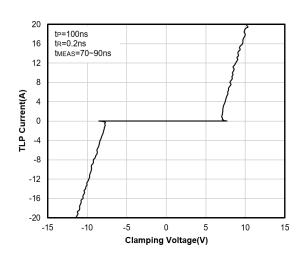
Clamping Voltage vs. Peak Pulse Current



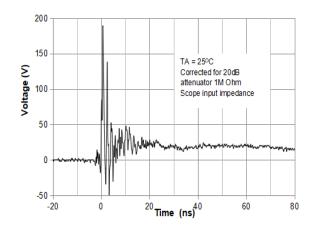
8 X 20µs Pulse Waveform



Peak Pulse Power vs. Pulse Time

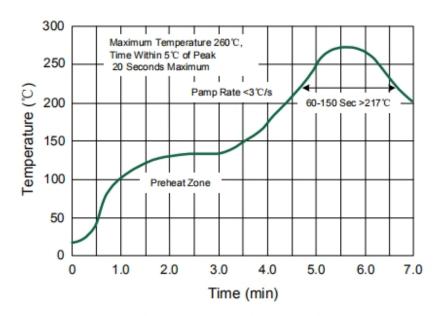


Power Derating Curve



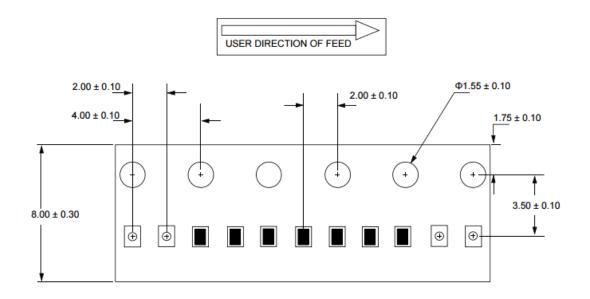
ESD Clamping Voltage 8 kV Contact per IEC61000-4-2

Re-flow Solder Profile



Lead-free Re-flow Solder Profile

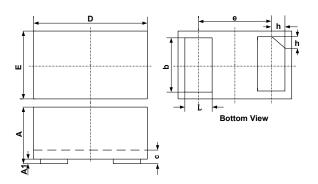
Tape and Reel Specification



Unit: mm

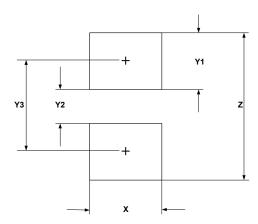


DFN0603-2 Package Outline Drawing



	DIMENSIONS		
0)/84	MILLIMETERS		
SYM	MIN	NOM	MAX
Α	0.230		0.330
A1	0.000	0.020	0.050
b	0.215	0.245	0.275
С	0.120	0.150	0.180
D	0.550	0.600	0.650
е		0.355 BS0	C
Е	0.250	0.300 0.35	
L	0.160	0.190	0.220
h	0.079 BSC		

Suggested Land Pattern



SYM	DIMENSIONS		
	MILLIMETERS	INCHES	
Х	0.30	0.012	
Y1	0.25	0.010	
Y2	0.15	0.006	
Y3	0.40	0.016	
Z	0.65	0.026	

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